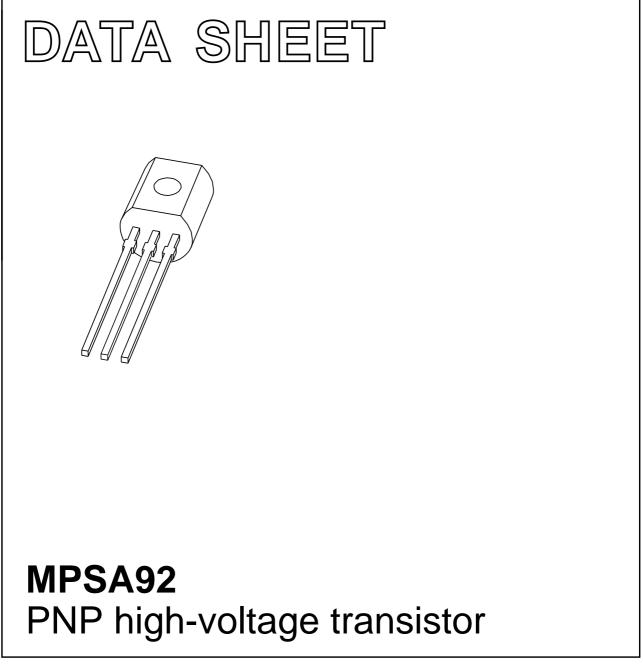
## DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 27 2001 Dec 07



#### FEATURES

- Low current (max. 100 mA)
- High voltage (max. 300 V).

#### APPLICATIONS

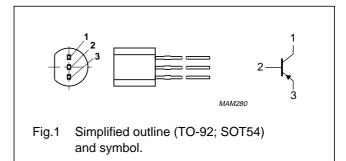
• General purpose switching and amplification.

#### DESCRIPTION

PNP high-voltage transistor in a TO-92; SOT54 plastic package. NPN complement: MPSA42.

#### PINNING

PIN	DESCRIPTION	
1	collector	
2	base	
3	emitter	



#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-300	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-300	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current (DC)		-	-100	mA
I <sub>CM</sub>	peak collector current		_	-200	mA
I <sub>BM</sub>	peak base current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	625	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

### MPSA92

### MPSA92

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	200	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	$I_E = 0; V_{CB} = -200 V$	-	-250	nA
I <sub>EBO</sub>	emitter cut-off current	$I_{\rm C} = 0; V_{\rm BE} = -3 \text{ V}$	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -10 V; note 1			
		$I_{\rm C} = -1  \rm mA$	25	-	
		$I_{\rm C} = -10  {\rm mA}$	40	-	
		$I_{\rm C} = -30 \text{ mA}$	25	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -20 mA; I <sub>B</sub> = -2 mA; note 1	-	-500	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{\rm C} = -20 \text{ mA}; I_{\rm B} = -2 \text{ mA}; \text{ note } 1$	-	-900	mV
C <sub>c</sub>	collector capacitance	I <sub>E</sub> =i <sub>e</sub> = 0; V <sub>CB</sub> = -20 V; f = 1 MHz	-	6	pF
f <sub>T</sub>	transition frequency	$I_{C} = -10 \text{ mA}; V_{CE} = -20 \text{ V};$ f = 100 MHz	50	-	MHz

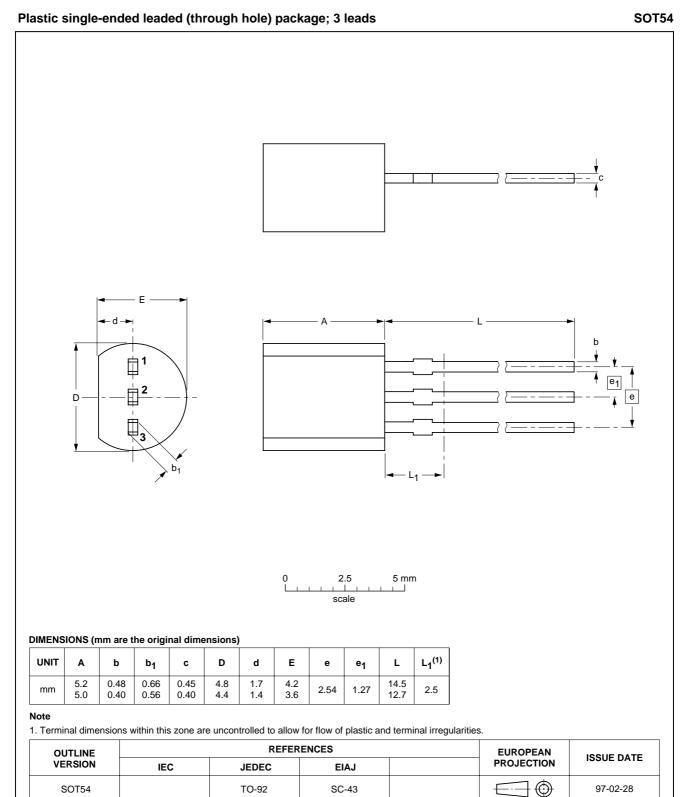
#### Note

1. Pulse test:  $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$ 

#### Product specification

### PNP high-voltage transistor

#### PACKAGE OUTLINE



MPSA92

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#### DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

#### Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Printed in The Netherlands

613514/04/pp**8** 

Date of release: 2001 Dec 07

Document order number: 9397 750 09141

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